

# Low frequency amplifier

## 2SB1695K

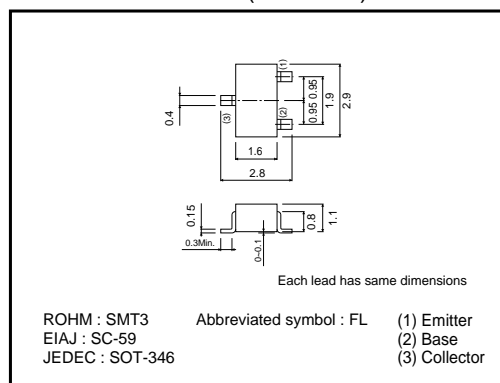
### ●Application

Low frequency amplifier  
Driver

### ●Features

- 1) A collector current is large.
- 2)  $V_{CE(sat)} \leq -370\text{mV}$   
At  $I_C = -1\text{A} / I_B = -50\text{mA}$

### ●External dimensions (Units : mm)



### ●Absolute maximum ratings (Ta=25°C)

| Parameter                    | Symbol    | Limits   | Unit |
|------------------------------|-----------|----------|------|
| Collector-base voltage       | $V_{CB0}$ | -30      | V    |
| Collector-emitter voltage    | $V_{CE0}$ | -30      | V    |
| Emitter-base voltage         | $V_{EB0}$ | -6       | V    |
| Collector current            | $I_C$     | -1.5     | A    |
|                              | $I_{CP}$  | -3       | A *  |
| Power dissipation            | $P_C$     | 200      | mW   |
| Junction temperature         | $T_j$     | 150      | °C   |
| Range of storage temperature | $T_{stg}$ | -55~+150 | °C   |

\*Single pulse,  $P_W=1\text{ms}$

### ●Packaging specifications

| Type     | Package                      | Taping |
|----------|------------------------------|--------|
|          | Code                         | T146   |
|          | Basic ordering unit (pieces) | 3000   |
| 2SB1695K |                              | ○      |

### ●Electrical characteristics (Ta=25°C)

| Parameter                            | Symbol        | Min. | Typ. | Max. | Unit | Conditions   |
|--------------------------------------|---------------|------|------|------|------|--|
| Collector-base breakdown voltage     | $BV_{CB0}$    | -30  | -    | -    | V    | $I_C = -10\mu\text{A}$   |
| Collector-emitter breakdown voltage  | $BV_{CE0}$    | -30  | -    | -    | V    | $I_C = -1\text{mA}$  |
| Emitter-base breakdown voltage       | $BV_{EB0}$    | -6   | -    | -    | V    | $I_E = -10\mu\text{A}$   |
| Collector cutoff current             | $I_{CBO}$     | -    | -    | -100 | nA   | $V_{CB} = -30\text{V}$   |
| Emitter cutoff current               | $I_{EBO}$     | -    | -    | -100 | nA   | $V_{EB} = -6\text{V}$  |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | -    | -200 | -370 | mV   | $I_C = -1\text{A}, I_B = -50\text{mA}$                         |
| DC current gain                      | $h_{FE}$      | 270  | -    | 680  | -    | $V_{CE} = -2\text{V}, I_C = -100\text{mA}$ *                   |
| Transition frequency                 | $f_T$         | -    | 280  | -    | MHz  | $V_{CE} = -2\text{V}, I_E = 100\text{mA}, f = 100\text{MHz}$ * |
| Corrector output capacitance         | $C_{ob}$      | -    | 13   | -    | pF   | $V_{CB} = -10\text{V}, I_E = 0\text{A}, f = 1\text{MHz}$       |

\* Pulsed

Transistors

●Electrical characteristic curves

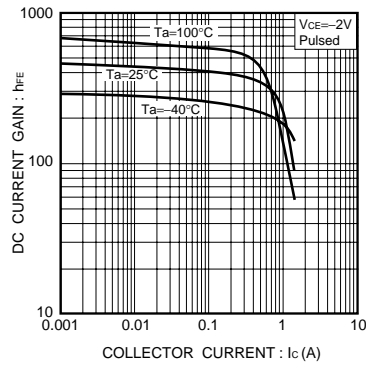


Fig.1 DC current gain vs. collector current

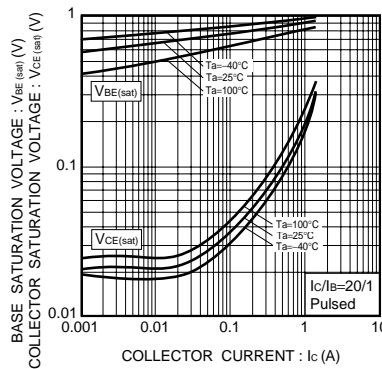


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

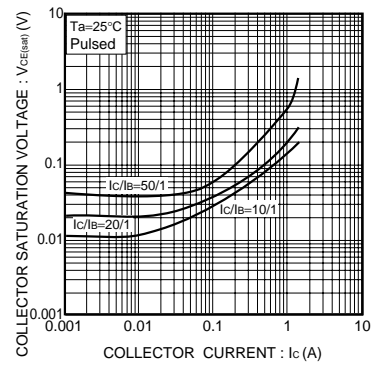


Fig.3 Collector-emitter saturation voltage vs. collector current

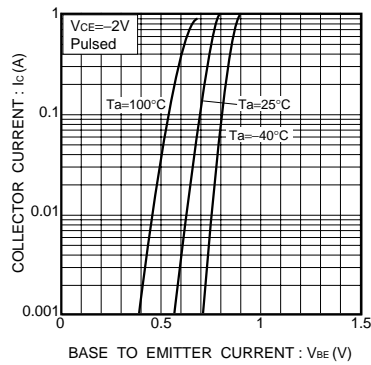


Fig.4 Grounded emitter propagation characteristics

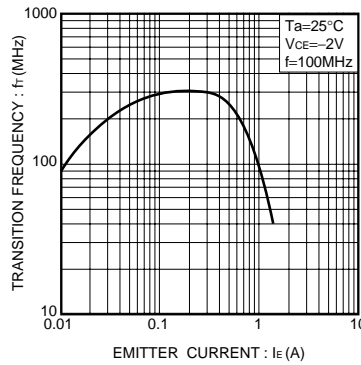


Fig.5 Gain bandwidth product vs. emitter current

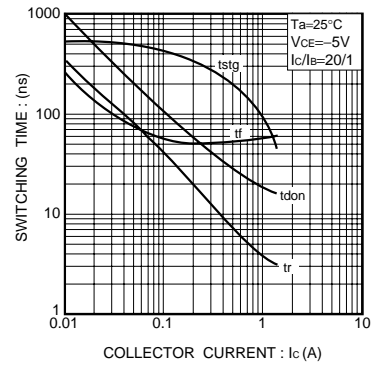


Fig.6 Switching time

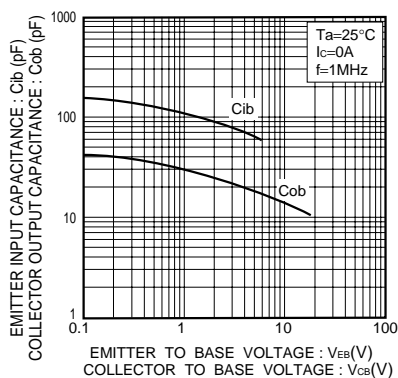


Fig.7 Collector output capacitance vs. collector-base voltage  
Emitter input capacitance vs. emitter-base voltage

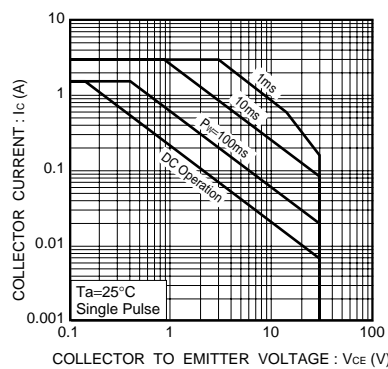


Fig.8 Safe Operating Area

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